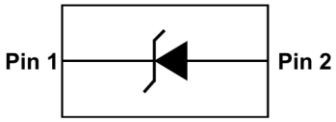
SSCT7V021N1

1-Line Uni-directional TVS Diode

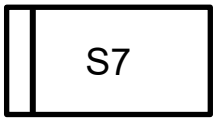
Description

The SSCT7V021N1 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The SSCT7V021N1 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge.

PIN configuration



Top view



Marking

Features

- Protects one I/O or Power Line
- DFN1006-2L Package
- Working voltage:7V
- Low Leakage Current
- Small Body Outine Dimensions
- Response Time is Typically<1ns
- Complies with following standards:
  -IEC61000-4-2(ESD) ±30Kv(contact),
  ±30kV(air)
  -IEC61000-4-4(EFT) 40A(5/50ns)
  -IEC61000-4-5(Lightning) 40A(8/20μs)

Applications

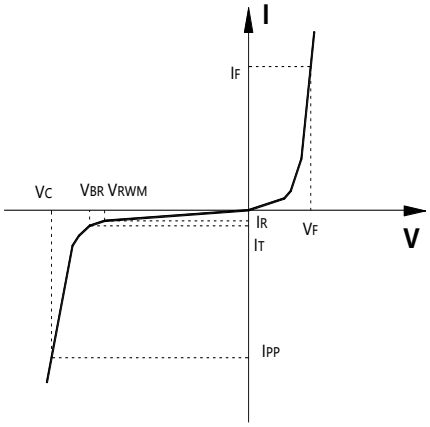
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays

Mechanical Characteristics

- Package: DFN1006-2L
- Case Material：“Green” Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per-J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

- **Electronic Parameter**

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C_J	Junction Capacitance



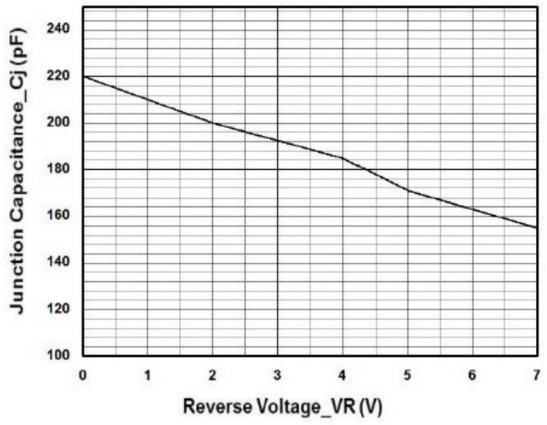
- **Absolute maximum rating @TA=25℃**

Parameter	Symbol	Value	Units
Peak Pulse Power（8/20μs）	P_{PP}	600	W
Peak Pulse Current（8/20μs）	I_{PP}	40	A
ESD Rating per IEC61000-4-2: Contact Air	V_{ESD}	±30 ±30	KV
Storage Temperature	T_{STG}	-55/+150	℃
Operating Temperature	T_J	-55/+125	℃

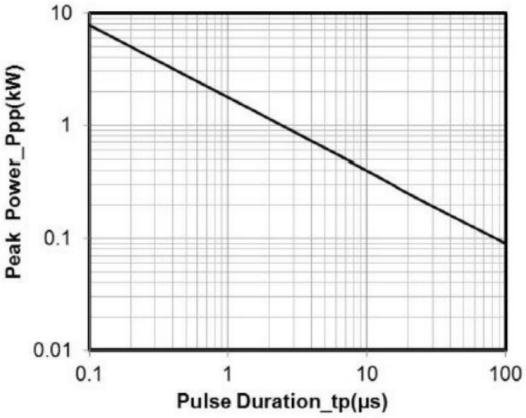
- **Electrical Characteristics @TA=25℃**

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}				7	V
Breakdown Voltage	V_{BR}	I_T = 1mA	7.5			V
Reverse Leakage Current	I_R	V_{RWM} =7V			0.2	μA
Forward Voltage	V_F	I_F =10mA			1.2	V
Clamping Voltage	V_C	I_{PP} =4A, t_P = 8/20μs			9	V
Clamping Voltage	V_C	I_{PP} =40A, t_P = 8/20μs			14	V
Junction Capacitance	C_J	V_R = 0V, f = 1MHz,		220		pF

- **Typical Performance Characteristics (T_A=25℃ unless otherwise Specified)**



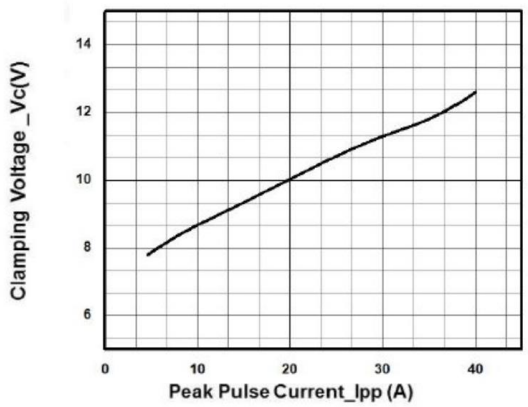
Junction Capacitance vs. Reverse Voltage



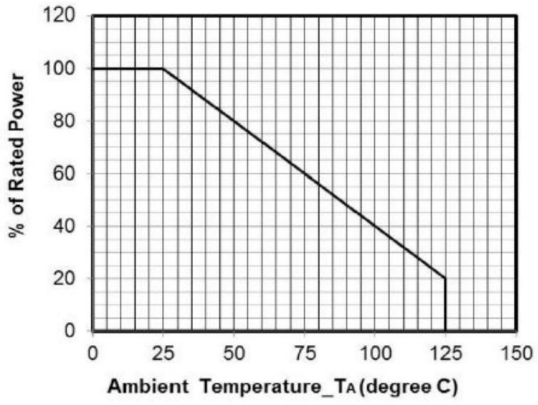
Peak Pulse Power vs. Pulse Time

Junction Capacitance vs. Reverse Voltage

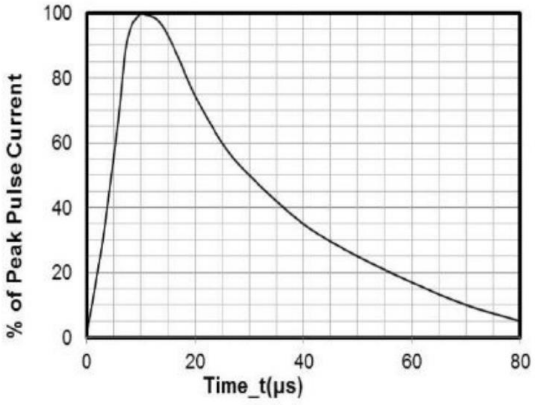
Peak Pulse Power vs. Pulse Time



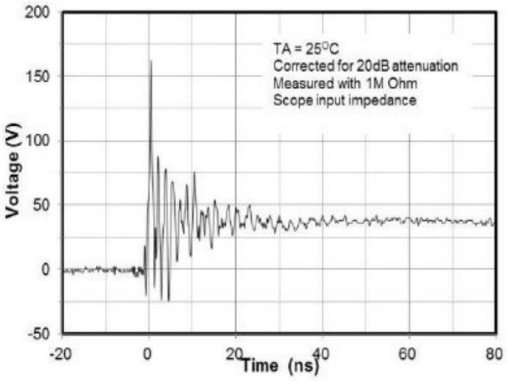
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



8 X 20μs Pulse Waveform



ESD Clamping Voltage

8 kV Contact per IEC61000−4−2

- **Package Information**

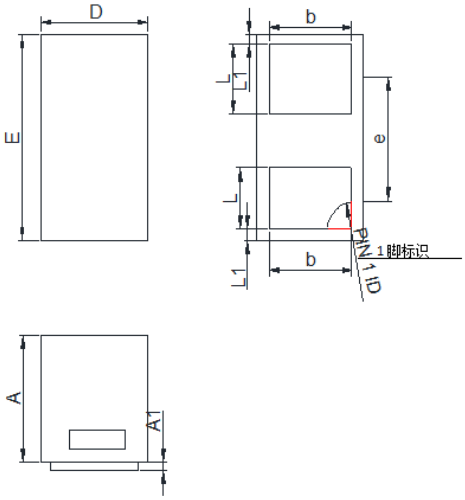
Ordering Information

Device	Package	Qty per Reel	Reel Size
SSCT7V021N1	DFN1006-2L	10000	7 Inch

Mechanical Data

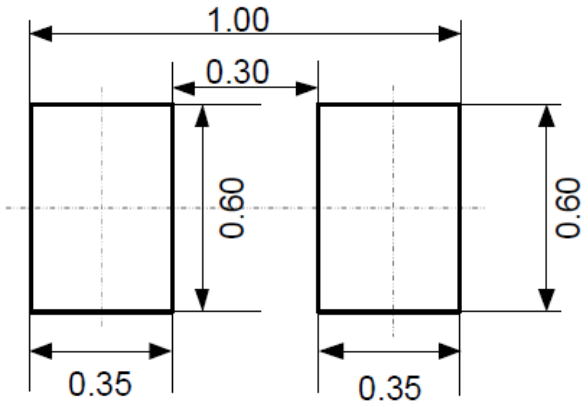
Case: DFN1006-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters	
	Min	Max
A	0.45	0.55
A1	0.00	0.05
D	0.55	0.65
E	0.95	1.05
b	0.45	0.60
e	0.65TYP	
L	0.2	0.3
L1	0.05REF	

Suggested Land Pattem



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